

# TLP291(SE

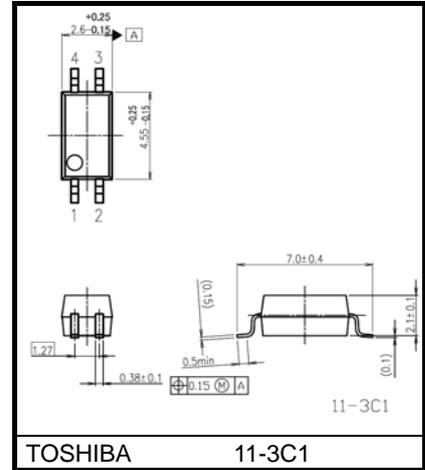
**Power Supplies**  
**Programmable Controllers**  
**Hybrid ICs**

TLP291(SE consists of photo transistor optically coupled to a gallium arsenide infrared emitting diode. TLP291(SE is housed in the SO4 package, very small and thin coupler. Since TLP291(SE is guaranteed wide operating temperature (Ta=-55 to 110 °C) and high isolation voltage (3750Vrms), it's suitable for high-density surface mounting applications such as small switching power supplies and programmable controllers.

- Collector-Emitter Voltage : 80 V (min)
- Current Transfer Ratio : 50% (min)  
     Rank GB : 100% (min)
- Isolation Voltage : 3750 Vrms (min)
- Operation temperature: -55 to 110 °C
- UL recognized : UL1577, File No. E67349
- cUL approved : CSA Component Acceptance Service No.5A,  
     File No. E67349
- SEMKO conformity : EN 60065: 2002,  
     EN 60950-1: 2001, EN 60335-1: 2002,
- BSI conformity : BS EN 60065: 2002,  
     BS EN 60950-1: 2006
- VDE conformity: EN 60747-5-5

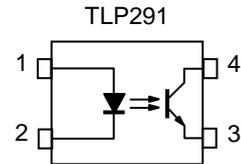
Construction Mechanical Rating  
 Creepage distance: 5.0mm(min)  
 Clearance: 5.0mm(min)  
 Insulation thickness: 0.4mm(min)

Unit: mm



Weight: 0.05 g (typ.)

**Pin Configuration**



- 1:ANODE
- 2:CATHODE
- 3:EMITTER
- 4:COLLECTOR

## Current Transfer Ratio (CTR) Rank ( Unless otherwise specified, Ta = 25°C)

| TYPE   | Classification<br>(Note1) | Current Transfer Ratio (%)<br>( $I_C / I_F$ )                      |     | Marking of Classification          |
|--------|---------------------------|--|-----|------------------------------------|
|        |                           | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}, T_a = 25^\circ\text{C}$ |     |                                    |
|        |                           | Min  | Max |                                    |
| TLP291 | Blank                     | 50   | 600 | Blank, YE, GR, GB, BL, Y+, G, G+,B |
|        | Rank Y                    | 50   | 150 | YE                                 |
|        | Rank GR                   | 100  | 300 | GR                                 |
|        | Rank GB                   | 100  | 600 | GB                                 |
|        | Rank BL                   | 200  | 600 | BL                                 |
|        | Rank YH                   | 75   | 150 | Y+                                 |
|        | Rank GRL                  | 100  | 200 | G                                  |
|        | Rank GRH                  | 150  | 300 | G+                                 |
|        | Rank BLL                  | 200  | 400 | B                                  |

Note1: Specify both the part number and a rank in this format when ordering

(e.g.) rank GB: TLP291 (GB,SE)

For safety standard certification, however, specify the part number alone.

(e.g.)TLP291 (GB,SE: TLP291

## Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25°C)

| CHARACTERISTIC                                    |   | SYMBOL                   | NOTE     | RATING     | UNIT    |
|---|---|--------------------------|----------|------------|---------|
| LED   | Input forward current                         | $I_F$                    |          | 50         | mA      |
|   | Input forward current derating (Ta≥90°C)      | $\Delta I_F / \Delta Ta$ |          | -1.5       | mA / °C |
|   | Input forward current (pulsed )               | $I_{FP}$                 | (Note 2) | 1          | A       |
|   | Input reverse voltage                         | $V_R$                    |          | 5          | V       |
|   | Input power dissipation                       | $P_D$                    |          | 100        | mW      |
|   | Input power dissipation derating (Ta ≥ 90°C)  | $\Delta P_D / \Delta Ta$ |          | -3.0       | mW / °C |
|   | Junction temperature                          | $T_j$                    |          | 125        | °C      |
| DETECTOR  | Collector-emitter voltage                     | $V_{CEO}$                |          | 80         | V       |
|   | Emitter-collector voltage                     | $V_{ECO}$                |          | 7          | V       |
|   | Collector current                             | $I_C$                    |          | 50         | mA      |
|   | Collector power dissipation                   | $P_C$                    |          | 150        | mW      |
|   | Collector power dissipation derating(Ta≥25°C) | $\Delta P_C / \Delta Ta$ |          | -1.5       | mW / °C |
|   | Junction temperature                          | $T_j$                    |          | 125        | °C      |
| Operating temperature range                       |   | $T_{opr}$                |          | -55 to 110 | °C      |
| Storage temperature range                         |   | $T_{stg}$                |          | -55 to 125 | °C      |
| Lead soldering temperature                        |   | $T_{sol}$                |          | 260 (10s)  | °C      |
| Total package power dissipation                   |   | $P_T$                    |          | 200        | mW      |
| Total package power dissipation derating(Ta≥25°C) |   | $\Delta P_T / \Delta Ta$ |          | -2.0       | mW / °C |
| Isolation voltage                                 |   | $BV_S$                   | (Note3)  | 3750       | Vrms    |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note2: Pulse width  $\leq 100\mu s$ , frequency 100Hz

Note3: AC, 1 minute, R.H.≤60%, Device considered a two terminal device: LED side pins shorted together and DETECTOR side pins shorted together.

## Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

| CHARACTERISTIC                |                                     | SYMBOL                               | TEST CONDITION                            | MIN | TYP. | MAX  | UNIT    |
|-------------------------------|-------------------------------------|--------------------------------------|---|-----|------|------|---------|
| LED                           | Input forward voltage               | $V_F$                                | $I_F = 10 \text{ mA}$                     | 1.1 | 1.25 | 1.4  | V       |
|                               | Input reverse current               | $I_R$                                | $V_R = 5 \text{ V}$                       | -   | -    | 5    | $\mu A$ |
|                               | Input capacitance                   | $C_T$                                | $V = 0 \text{ V}, f = 1 \text{ MHz}$      | -   | 30   | -    | pF      |
| DETECTOR                      | Collector-emitter breakdown voltage | $V_{(BR) CEO}$                       | $I_C = 0.5 \text{ mA}$                    | 80  | -    | -    | V       |
|                               | Emitter-collector breakdown voltage | $V_{(BR) ECO}$                       | $I_E = 0.1 \text{ mA}$                    | 7   | -    | -    | V       |
|                               | Dark current                        | $I_{DARK}$                           | $V_{CE} = 48 \text{ V}$                   | -   | 0.01 | 0.08 | $\mu A$ |
|                               |                                     |                                      | $V_{CE} = 48 \text{ V}, T_a = 85^\circ C$ | -   | 2    | 50   | $\mu A$ |
| Collector-emitter capacitance | $C_{CE}$                            | $V = 0 \text{ V}, f = 1 \text{ MHz}$ | -   | 10  | -    | pF   |         |

**Coupled Electrical Characteristics (Unless otherwise specified, Ta = 25°C)**

| CHARACTERISTIC                       | SYMBOL                   | TEST CONDITION  | MIN | TYP. | MAX | UNIT          |
|--------------------------------------|--------------------------|---|-----|------|-----|---------------|
| Current transfer ratio               | $I_C / I_F$              | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$<br>Rank GB   | 50  | -    | 600 | %             |
|                                      |                          |   | 100 | -    | 600 |               |
| Saturated current transfer ratio     | $I_C / I_F (\text{sat})$ | $I_F = 1 \text{ mA}, V_{CE} = 0.4 \text{ V}$<br>Rank GB   | -   | 60   | -   | %             |
|                                      |                          |   | 30  | -    | -   |               |
| Collector-emitter saturation voltage | $V_{CE (\text{sat})}$    | $I_C = 2.4 \text{ mA}, I_F = 8 \text{ mA}$<br>$I_C = 0.2 \text{ mA}, I_F = 1 \text{ mA}$<br>Rank GB | -   | -    | 0.3 | V             |
|                                      |                          |   | -   | 0.2  | -   |               |
|                                      |                          |   | -   | -    | 0.3 |               |
| OFF-state collector current          | $I_C (\text{off})$       | $V_F = 0.7 \text{ V}, V_{CE} = 48 \text{ V}$  | -   | -    | 10  | $\mu\text{A}$ |

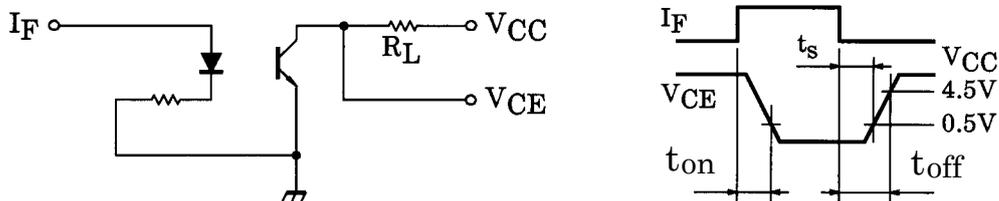
**Isolation Characteristics (Unless otherwise specified, Ta = 25°C)**

| CHARACTERISTIC                      | SYMBOL | TEST CONDITION                               | MIN                | TYP.      | MAX | UNIT     |
|-------------------------------------|--------|--|--------------------|-----------|-----|----------|
| Total capacitance (input to output) | $C_S$  | $V_S = 0 \text{ V}, f = 1 \text{ MHz}$       | -                  | 0.8       | -   | pF       |
| Isolation resistance                | $R_S$  | $V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$ | $1 \times 10^{12}$ | $10^{14}$ | -   | $\Omega$ |
| Isolation voltage                   | $BV_S$ | AC, 1 minute                                 | 3750               | -         | -   | Vrms     |
|                                     |        | AC, 1 second, in OIL                         | -                  | 10000     | -   | Vdc      |
|                                     |        | DC, 1 minute, in OIL                         | -                  | 10000     | -   | Vdc      |

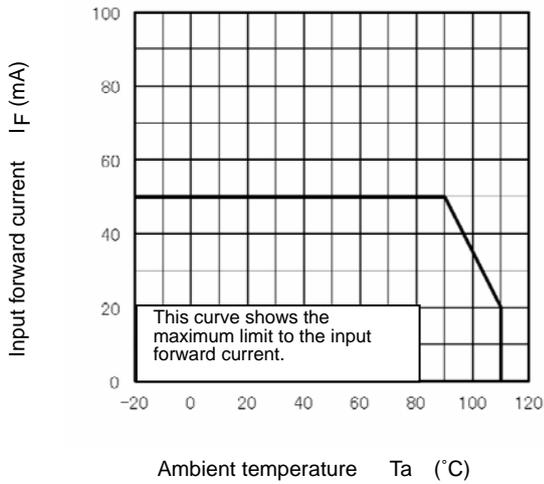
**Switching Characteristics (Unless otherwise specified, Ta = 25°C)**

| CHARACTERISTIC | SYMBOL    | TEST CONDITION   | MIN | TYP. | MAX | UNIT          |
|----------------|-----------|--|-----|------|-----|---------------|
| Rise time      | $t_r$     | $V_{CC} = 10 \text{ V}, I_C = 2 \text{ mA}$<br>$R_L = 100 \Omega$                  | -   | 2    | -   | $\mu\text{s}$ |
| Fall time      | $t_f$     |  | -   | 3    | -   |               |
| Turn-on time   | $t_{on}$  |  | -   | 3    | -   |               |
| Turn-off time  | $t_{off}$ |  | -   | 3    | -   |               |
| Turn-on time   | $t_{on}$  | $R_L = 1.9 \text{ k}\Omega$<br>$V_{CC} = 5 \text{ V}, I_F = 16 \text{ mA}$ (Fig.1) | -   | 0.5  | -   | $\mu\text{s}$ |
| Storage time   | $t_s$     |  | -   | 25   | -   |               |
| Turn-off time  | $t_{off}$ |  | -   | 40   | -   |               |

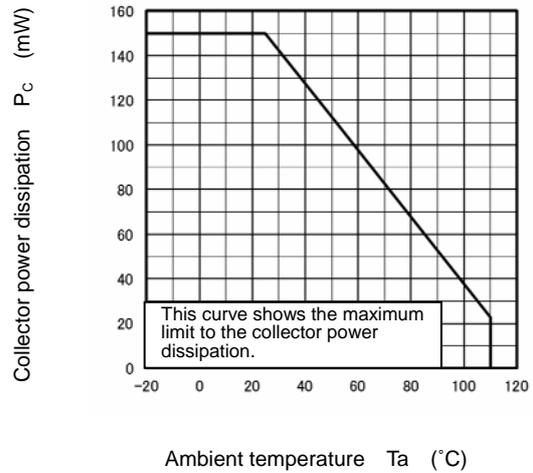
(Fig.1) Switching Time Test Circuit



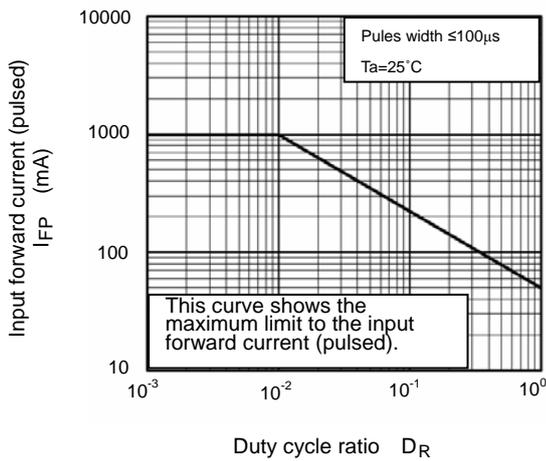
$I_F - T_a$



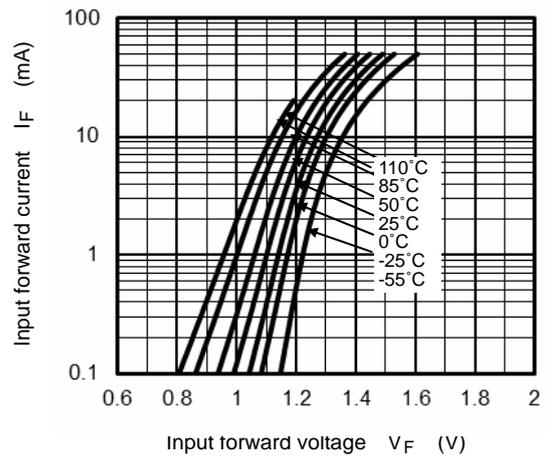
$P_C - T_a$



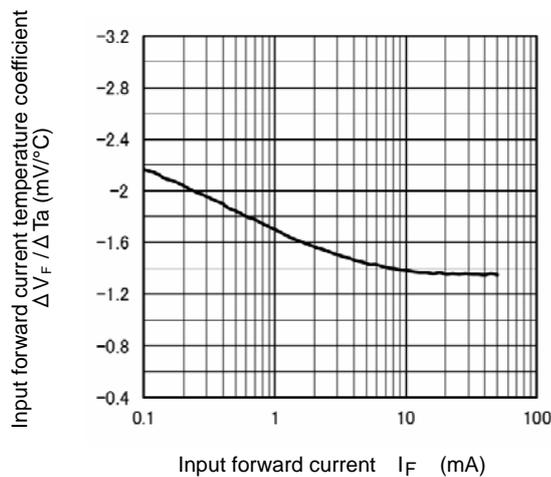
$I_{FP} - D_R$



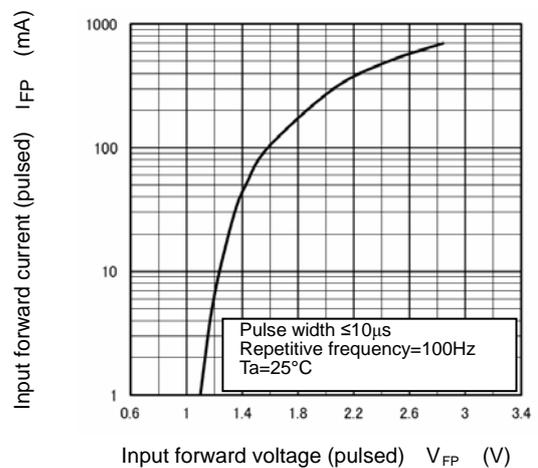
$I_F - V_F$



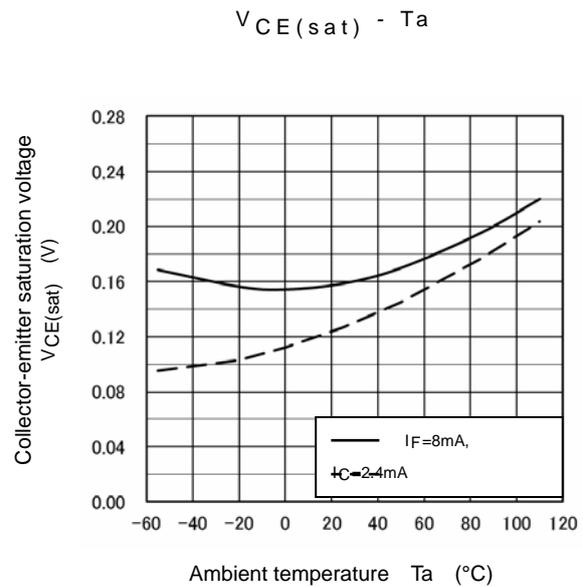
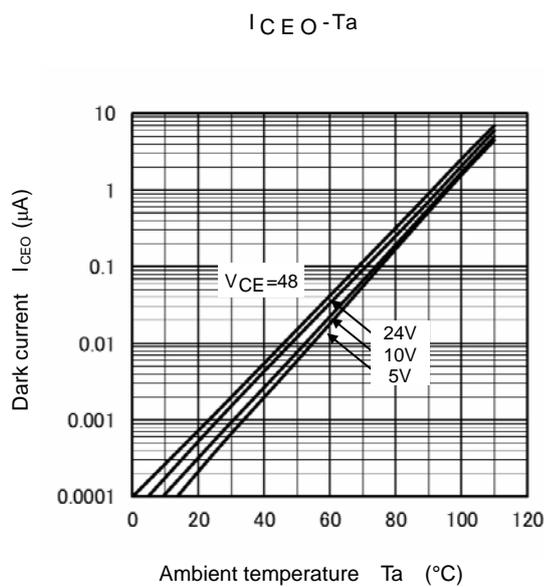
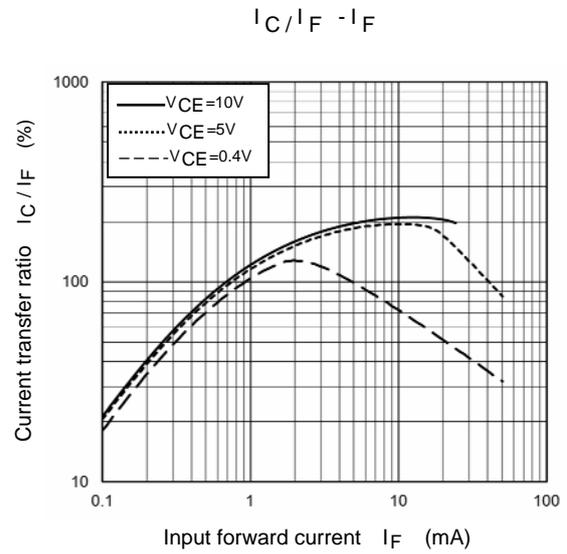
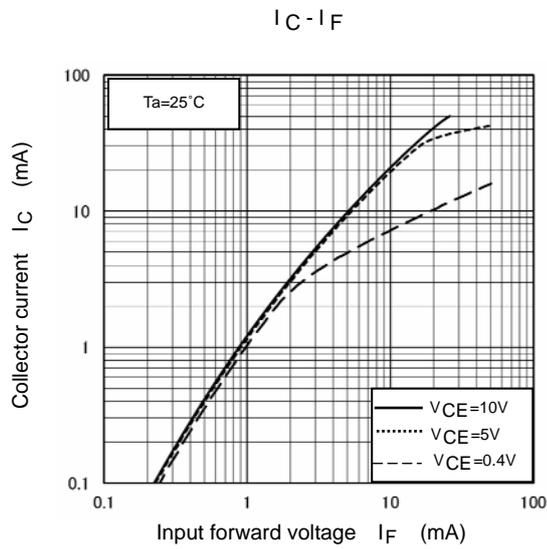
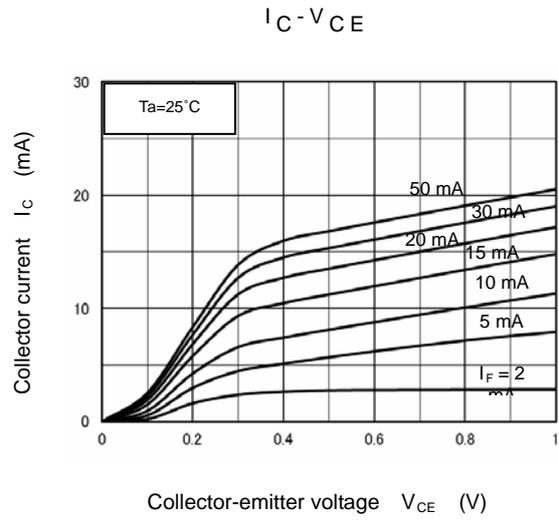
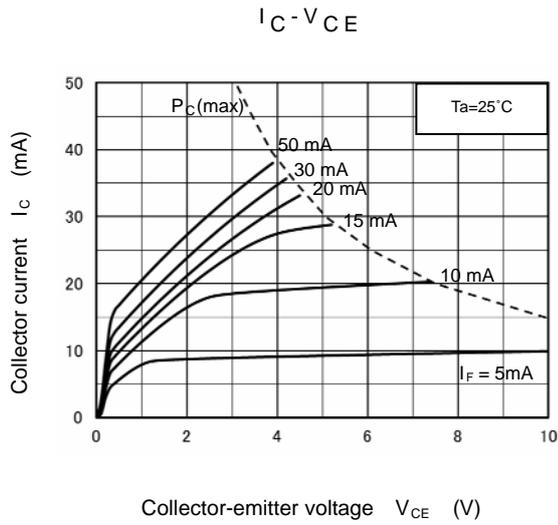
$\Delta V_F / \Delta T_a - I_F$



$I_{FP} - V_{FP}$

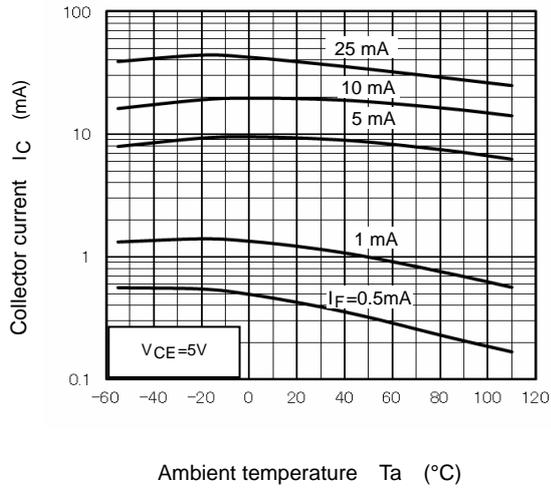


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted

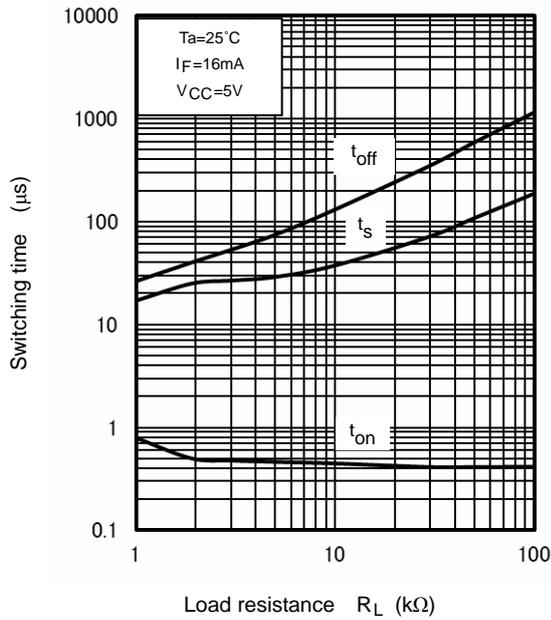


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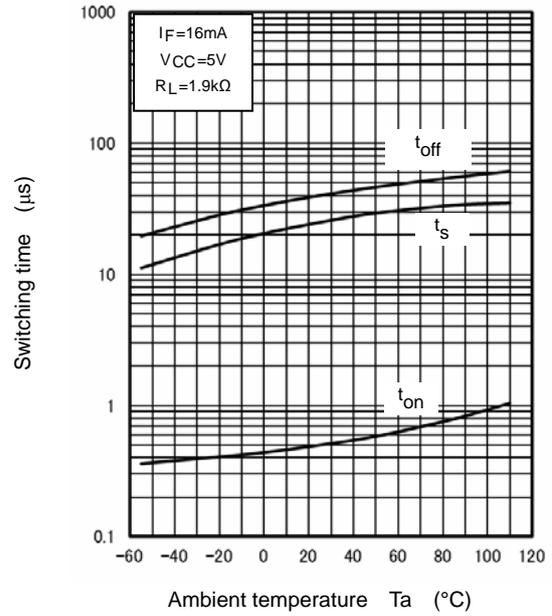
$I_C - T_a$



Switching time -  $R_L$



Switching time -  $T_a$



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## Soldering and Storage

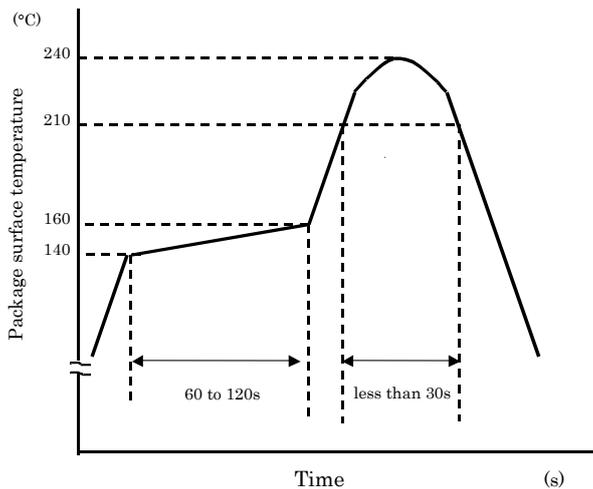
### 1. Soldering

#### 1.1 Soldering

When using a soldering iron or medium infrared ray/hot air reflow, avoid a rise in device temperature as much as possible by observing the following conditions.

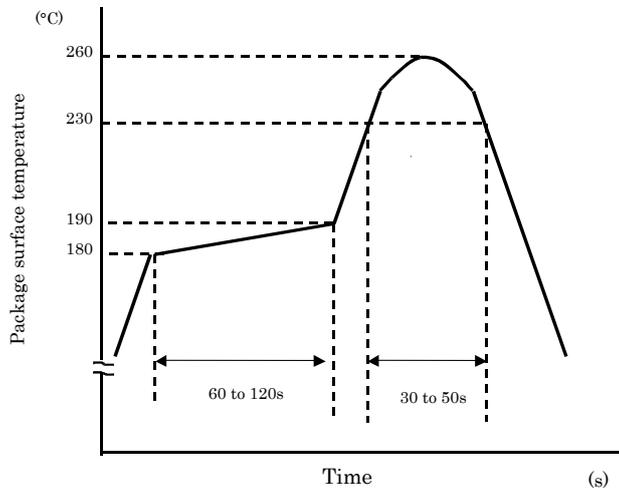
#### 1) Using solder reflow

·Temperature profile example of lead (Pb) solder



This profile is based on the device's maximum heat resistance guaranteed value. Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

·Temperature profile example of using lead (Pb)-free solder



This profile is based on the device's maximum heat resistance guaranteed value. Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

#### 2) Using solder flow (for lead (Pb) solder, or lead (Pb)-free solder)

- Please preheat it at 150°C between 60 and 120 seconds.
- Complete soldering within 10 seconds below 260°C. Each pin may be heated at most once.

#### 3) Using a soldering iron

Complete soldering within 10 seconds below 260°C, or within 3 seconds at 350°C. Each pin may be heated at most once.

## 2. Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

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